



TS1871-TS1872-TS1874

1.8V input/output rail-to-rail
Low power operational amplifiers

Features

- Operating range from $V_{CC} = 1.8V$ to $6V$
- Rail-to-rail input and output
- Extended V_{icm} ($V_{DD} - 0.2V$ to $V_{CC} + 0.2V$)
- Low supply current ($400\mu A$)
- Gain bandwidth product ($1.6MHz$)
- High unity gain stability
- ESD tolerance ($2kV$)
- Latch-up immunity
- Available in SOT23-5 micro package

Applications

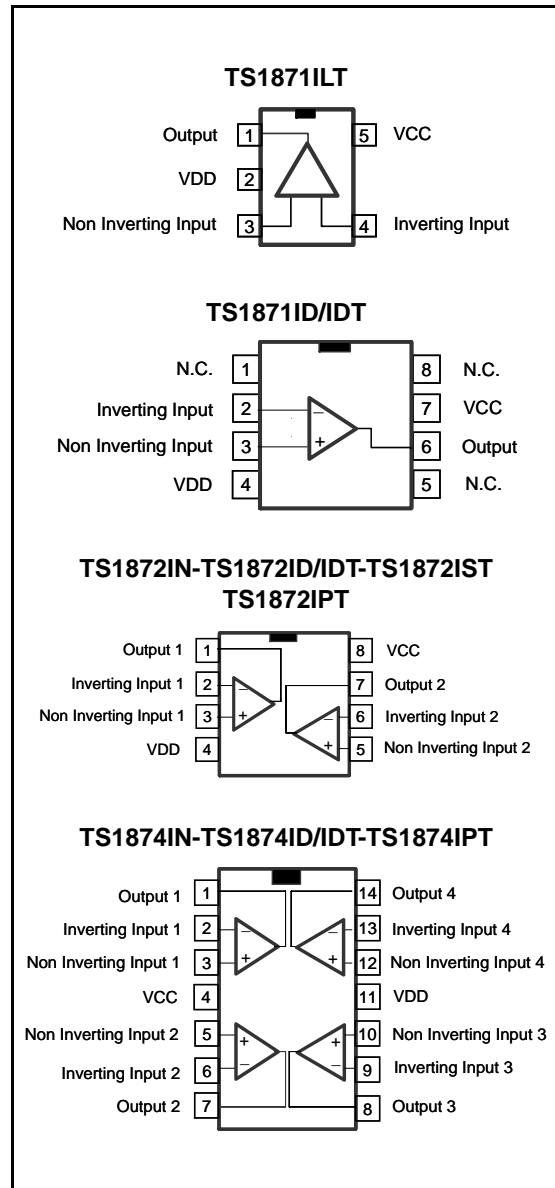
- Battery-powered applications (toys)
- Portable communication devices (cell phones)
- Audio driver (headphone drivers)
- Laptop/notebook computers

Description

The TS187x (single, dual & quad) is an operational amplifier family able to operate with voltages as low as $1.8V$ and features both input and output rail-to-rail.

The common mode input voltage extends $200mV$ beyond the supply voltages at $25^{\circ}C$ while the output voltage swing is within $100mV$ of each rail with 600Ω load resistor. This device consumes typically $400\mu A$ per channel while offering $1.6MHz$ of gain-bandwidth product. The amplifier provides high output drive capability typically at $65mA$ load.

These features make the TS187x family ideal for sensor interface, battery-supplied and portable applications.



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1 Absolute maximum ratings and operating conditions

Table 1. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V_{CC}	Supply voltage ⁽¹⁾	7	V
V_{id}	Differential input voltage ⁽²⁾	± 1	V
V_i	Input voltage	$V_{DD} - 0.3$ to $V_{CC} + 0.3$	V
T_{stg}	Storage temperature	-65 to +150	°C
T_j	Maximum junction temperature	150	°C
R_{thja}	Thermal resistance junction to ambient ⁽³⁾		°C/W
	SOT23-5	250	
	DIP8	85	
	DIP14	66	
	miniSO-8	190	
	SO-8	125	
	SO-14	103	
R_{thjc}	Thermal resistance junction to case		°C/W
	SOT23-5	81	
	DIP8	41	
	DIP14	33	
	miniSO-8	39	
	SO-8	40	
	SO-14	31	
ESD	HBM: human body model ⁽⁴⁾	2	kV
	MM: machine model ⁽⁵⁾	200	V
	CDM: charged device model ⁽⁶⁾	1.5	kV
	Latch-up immunity	200	mA
	Lead temperature (soldering, 10 sec)	250	°C
	Output short-circuit duration	see note ⁽⁷⁾	

- All voltage values, except differential voltage are with respect to network terminal.
- Differential voltages are the non-inverting input terminal with respect to the inverting input terminal. If $V_{id} > \pm 1V$, the maximum input current must not exceed $\pm 1mA$. When $V_{id} > \pm 1V$, add an input series resistor to limit input current.
- Short-circuits can cause excessive heating. Destructive dissipation can result from simultaneous short-circuits on all amplifiers.
- Human body model: A 100pF capacitor is charged to the specified voltage, then discharged through a 1.5k Ω resistor between two pins of the device. This is done for all couples of connected pin combinations while the other pins are floating.
- Machine model: A 200pF capacitor is charged to the specified voltage, then discharged directly between two pins of the device with no external series resistor (internal resistor < 5 Ω). This is done for all couples of connected pin combinations while the other pins are floating.
- Charged device model: all pins and the package are charged together to the specified voltage and then discharged directly to the ground through only one pin. This is done for all pins.
- Short-circuits from the output to V_{CC} can cause excessive heating. The maximum output current is approximately 80mA, independent of the magnitude of V_{CC} . Destructive dissipation can result from simultaneous short-circuits on all amplifiers.

Table 2. Operating conditions

Symbol	Parameter	Value	Unit
V_{CC}	Supply voltage	1.8 to 6	V
V_{icm}	Common mode input voltage range $T_{op} = 25^{\circ}\text{C}$, $1.8 \leq V_{CC} \leq 6\text{V}$ $T_{min} < T_{op} < T_{max}$, $1.8 \leq V_{CC} \leq 6\text{V}$	$V_{DD} - 0.2$ to $V_{CC} + 0.2$ V_{DD} to V_{CC}	V
T_{oper}	Operating free air temperature range	-40 to + 125	$^{\circ}\text{C}$

2 Electrical characteristics

Table 3. Electrical characteristics at $V_{CC} = +1.8V$ with $V_{DD} = 0V$, C_L & R_L connected to $V_{CC}/2$, and $T_{amb} = 25^\circ C$ (unless otherwise specified)⁽¹⁾

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
V_{io}	Input offset voltage	$V_{icm} = V_{out} = V_{CC}/2$ TS1871A/2A/4A $T_{min} \leq T_{amb} \leq T_{max}$ TS1871/2/4 $T_{min} \leq T_{amb} \leq T_{max}$		0.1	1 1.5 3 6	mV
ΔV_{io}	Input offset voltage drift			2		$\mu V/^\circ C$
I_{io}	Input offset current	$V_{icm} = V_{out} = V_{CC}/2$ ⁽²⁾ $T_{min} \leq T_{amb} \leq T_{max}$		3	30 60	nA
I_{ib}	Input bias current	$V_{icm} = V_{out} = V_{CC}/2$ ⁽¹⁾ $T_{min} \leq T_{amb} \leq T_{max}$		40	125 150	nA
CMR	Common mode rejection ratio $20 \log (\Delta V_{ic}/\Delta V_{io})$	$0 \leq V_{icm} \leq V_{CC}$, $V_{out} = V_{CC}/2$ $T_{min} \leq T_{amb} \leq T_{max}$	55 52	77		dB
A_{vd}	Large signal voltage gain	$V_{out} = 0.5V$ to $1.3V$ $R_L = 2k\Omega$ $R_L = 600\Omega$	77 70	92 85		dB
V_{OH}	High level output voltage	$V_{id} = 100mV$ $R_L = 2k\Omega$ $R_L = 600\Omega$ $T_{min} \leq T_{amb} \leq T_{max}$, $R_L = 2k\Omega$ $T_{min} \leq T_{amb} \leq T_{max}$, $R_L = 600\Omega$	1.65 1.62 1.65 1.62	1.77 1.74		V
V_{OL}	Low level output voltage	$V_{id} = -100mV$ $R_L = 2k\Omega$ $R_L = 600\Omega$ $T_{min} \leq T_{amb} \leq T_{max}$, $R_L = 2k\Omega$ $T_{min} \leq T_{amb} \leq T_{max}$, $R_L = 600\Omega$		88 115	100 150 100 150	mV
I_o	Output source current	$V_{ID} = 100mV$, $V_O = V_{DD}$	20	65		mA
	Output sink current	$V_{ID} = -100mV$, $V_O = V_{CC}$	20	65		
I_{CC}	Supply current (per amplifier)	$V_{out} = V_{CC}/2$ $A_{VCL} = 1$, no load $T_{min} \leq T_{amb} \leq T_{max}$		400	560 600	μA
GBP	Gain bandwidth product	$R_L = 10k\Omega$, $C_L = 100pF$, $f = 100kHz$	0.9	1.6		MHz
SR	Slew rate	$R_L = 10k\Omega$, $C_L = 100pF$, $A_V = 1$	0.38	0.54		$V/\mu s$
ϕ_m	Phase margin	$C_L = 100pF$		53		Degrees
e_n	Input voltage noise	$f = 1kHz$		27		nV/\sqrt{Hz}
THD	Total harmonic distortion			0.01		%

1. All parameter limits at temperatures different from $25^\circ C$ are guaranteed by correlation.

2. Maximum values include unavoidable inaccuracies of the industrial tests.

Table 4. Electrical characteristics at $V_{CC} = +3V$ with $V_{DD} = 0V$, C_L & R_L connected to $V_{CC}/2$, and $T_{amb} = 25^\circ C$ (unless otherwise specified)⁽¹⁾

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
V_{io}	Input offset voltage	$V_{icm} = V_{out} = V_{CC}/2$ TS1871A/2A/4A $T_{min} \leq T_{amb} \leq T_{max}$ TS1871/2/4 $T_{min} \leq T_{amb} \leq T_{max}$		0.1	1 1.5 3 6	mV
ΔV_{io}	Input offset voltage drift			2		$\mu V/^\circ C$
I_{io}	Input offset current	$V_{icm} = V_{out} = V_{CC}/2$ ⁽²⁾ $T_{min} \leq T_{amb} \leq T_{max}$		3	30 60	nA
I_{ib}	Input bias current	$V_{icm} = V_{out} = V_{CC}/2$ ⁽¹⁾ $T_{min} \leq T_{amb} \leq T_{max}$		4	125 150	nA
CMR	Common mode rejection ratio $20 \log (\Delta V_{ic}/\Delta V_{io})$	$0 \leq V_{icm} \leq V_{CC}$, $V_{out} = V_{CC}/2$ $T_{min} \leq T_{amb} \leq T_{max}$	60 57	80		dB
A_{vd}	Large signal voltage gain	$V_{out} = 0.5V$ to $2.5V$ $R_L = 2k\Omega$ $R_L = 600\Omega$	80 74	92 95		dB
V_{OH}	High level output voltage	$V_{ID} = 100mV$ $R_L = 2k\Omega$ $R_L = 600\Omega$ $T_{min} \leq T_{amb} \leq T_{max}$, $R_L = 2k\Omega$ $T_{min} \leq T_{amb} \leq T_{max}$, $R_L = 600\Omega$	2.82 2.80 2.82 2.80	2.95 2.95		V
V_{OL}	Low level output voltage	$V_{ID} = -100mV$ $R_L = 2k\Omega$ $R_L = 600\Omega$ $T_{min} \leq T_{amb} \leq T_{max}$, $R_L = 2k\Omega$ $T_{min} \leq T_{amb} \leq T_{max}$, $R_L = 600\Omega$		88 115	120 160 120 160	mV
I_o	Output source current	$V_{ID} = 100mV$, $V_O = V_{DD}$	20	80		mA
	Output sink current	$V_{ID} = -100mV$, $V_O = V_{CC}$	20	80		
I_{CC}	Supply current (per amplifier)	$V_{out} = V_{CC}/2$ $A_{VCL} = 1$, no load $T_{min} \leq T_{amb} \leq T_{max}$		450	650 690	μA
GBP	Gain bandwidth product	$R_L = 10k\Omega$, $C_L = 100pF$, $f = 100kHz$	1	1.7		MHz
SR	Slew rate	$R_L = 10k\Omega$, $C_L = 100pF$, $A_V = 1$	0.42	0.6		V/ μs
ϕ_m	Phase margin	$C_L = 100pF$		53		Degrees
e_n	Input voltage noise	$f = 1kHz$		27		nV/ \sqrt{Hz}
THD	Total harmonic distortion			0.01		%

1. All parameter limits at temperatures different from $25^\circ C$ are guaranteed by correlation.

2. Maximum values include unavoidable inaccuracies of the industrial tests.

**Table 5. Electrical characteristics at $V_{CC} = +5V$
with $V_{DD} = 0V$, C_L & R_L connected to $V_{CC}/2$, and $T_{amb} = 25^\circ C$ (unless otherwise specified) ⁽¹⁾**

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
V_{io}	Input offset voltage	$V_{icm} = V_{out} = V_{CC}/2$ TS1871A/2A/4A $T_{min} \leq T_{amb} \leq T_{max}$ TS1871/2/4 $T_{min} \leq T_{amb} \leq T_{max}$		0.1	1 1.5 3 6	mV
ΔV_{io}	Input offset voltage drift			2		$\mu V/^\circ C$
I_{io}	Input offset current	$V_{icm} = V_{out} = V_{CC}/2$ ⁽²⁾ $T_{min} \leq T_{amb} \leq T_{max}$		3	30 60	nA
I_{ib}	Input bias current	$V_{icm} = V_{out} = V_{CC}/2$ ⁽¹⁾ $T_{min} \leq T_{amb} \leq T_{max}$		70	130 150	nA
CMR	Common mode rejection ratio $20 \log (\Delta V_{ic}/\Delta V_{io})$	$0 \leq V_{icm} \leq V_{CC}$, V_{out} different from $V_{CC}/2$ $T_{min} \leq T_{amb} \leq T_{max}$	65 62	85		dB
SVR	Supply voltage rejection ratio $20 \log (\Delta V_{cc}/\Delta V_{io})$	$V_{CC} = 1.8$ to $5V$	70	90		dB
A_{vd}	Large signal voltage gain	$V_{out} = 1V$ to $4V$ $R_L = 2k\Omega$ $R_L = 600\Omega$	83 77	92 85		dB
V_{OH}	High level output voltage	$V_{ID} = 100mV$ $R_L = 2k\Omega$ $R_L = 600\Omega$ $T_{min} \leq T_{op} \leq T_{max}$, $R_L = 2k\Omega$ $T_{min} \leq T_{op} \leq T_{max}$, $R_L = 600\Omega$	4.80 4.75 4.80 4.75	4.95 4.90		V
V_{OL}	Low level output voltage	$V_{ID} = -100mV$ $R_L = 2k\Omega$ $R_L = 600\Omega$ $T_{min} \leq T_{op} \leq T_{max}$, $R_L = 2k\Omega$ $T_{min} \leq T_{op} \leq T_{max}$, $R_L = 600\Omega$		88 115	130 188 130 188	mV
I_o	Output source current	$V_{ID} = 100mV$, $V_O = V_{DD}$	20	80		mA
	Output sink current	$V_{ID} = -100mV$, $V_O = V_{CC}$	20	80		
I_{CC}	Supply current (per amplifier)	$V_{out} = V_{CC}/2$ $A_{VCL} = 1$, no load $T_{min} \leq T_{amb} \leq T_{max}$		500	835 875	μA
GBP	Gain bandwidth product	$R_L = 10k\Omega$, $C_L = 100pF$, $f = 100kHz$	1	1.8		MHz
SR	Slew rate	$R_L = 10k\Omega$, $C_L = 100pF$, $A_V = 1$	0.42	0.6		$V/\mu s$
ϕ_m	Phase margin	$C_L = 100pF$		55		Degrees
en	Input voltage noise	$f = 1kHz$		27		nV/\sqrt{Hz}
THD	Total harmonic distortion			0.01		%

1. All parameter limits at temperatures different from $25^\circ C$ are guaranteed by correlation.
2. Maximum values include unavoidable inaccuracies of the industrial tests.

Figure 1. Input offset voltage distribution

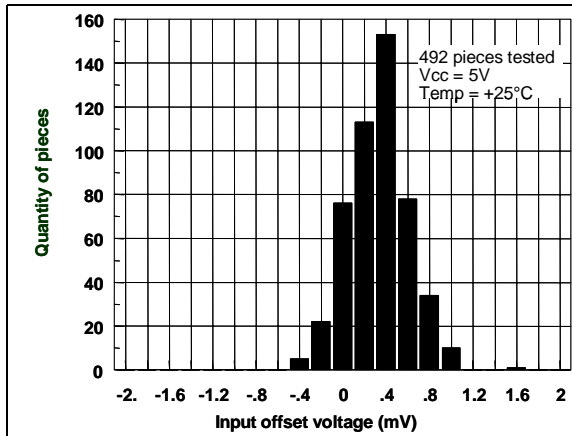


Figure 2. Input offset voltage vs. temperature

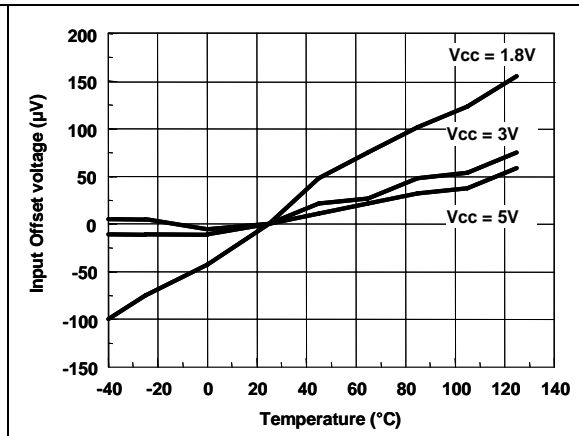


Figure 3. Input bias current vs. temperature

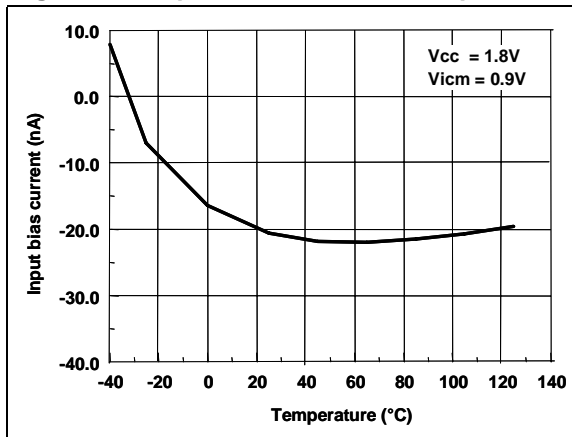


Figure 4. Input bias current vs. temperature

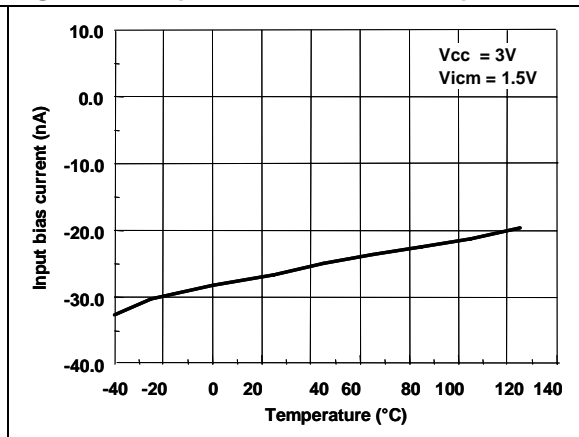


Figure 5. Supply current/amplifier vs. supply voltage

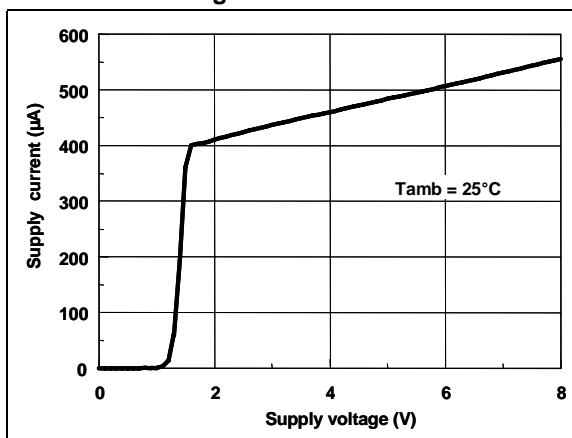


Figure 6. Supply current/amplifier vs. temperature

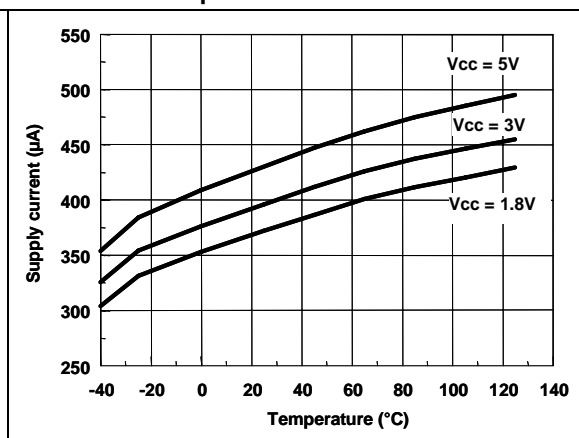


Figure 7. Common mode rejection vs. temperature

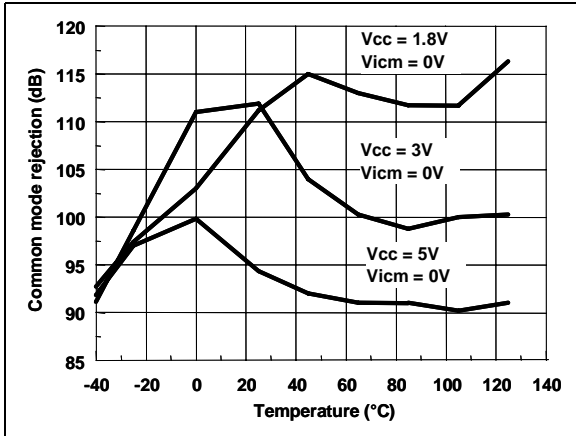


Figure 8. Supply voltage rejection vs. temperature

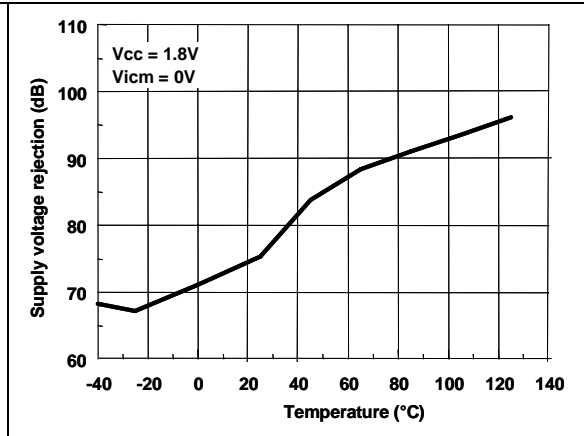


Figure 9. Supply voltage rejection vs. temperature

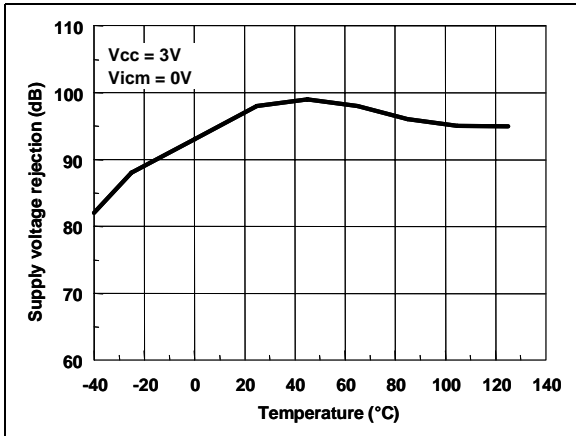


Figure 10. Supply voltage rejection vs. temperature

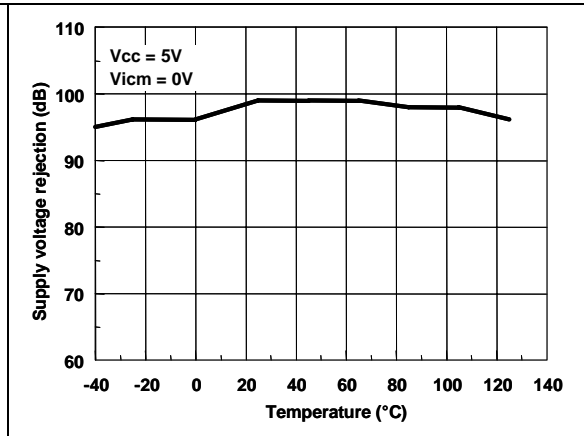


Figure 11. Power supply voltage rejection vs. frequency

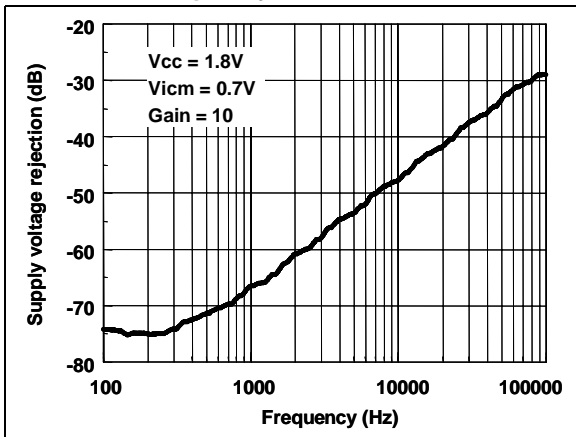


Figure 12. Open loop gain vs. frequency

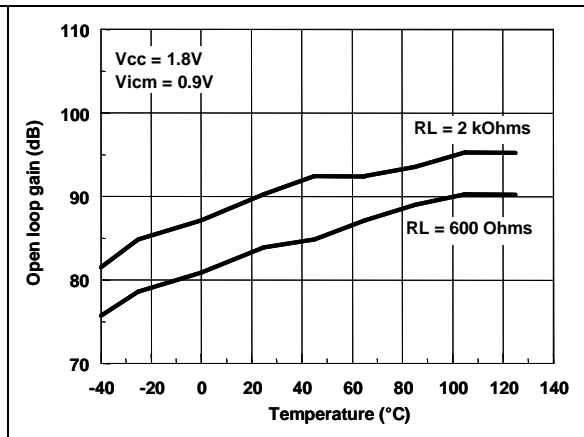


Figure 13. Open loop gain vs. temperature

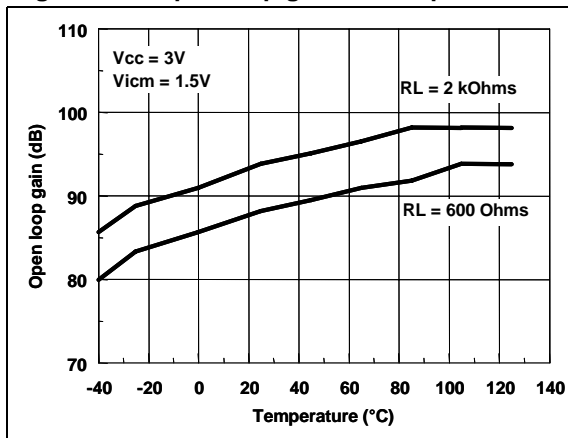


Figure 14. Open loop gain vs. temperature

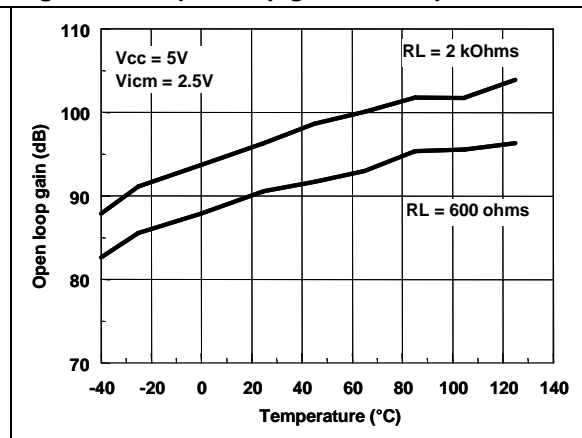


Figure 15. High level output voltage vs. temperature

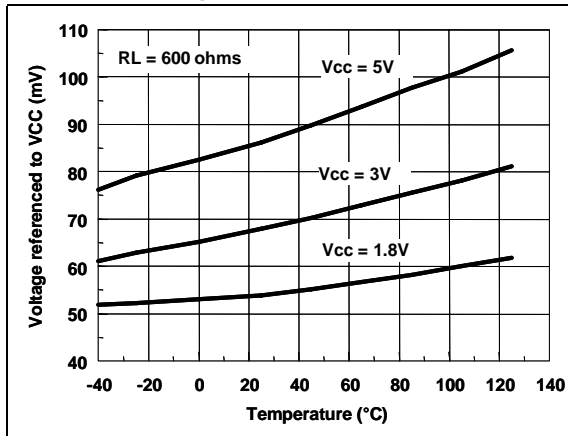


Figure 16. Low level output voltage vs. temperature

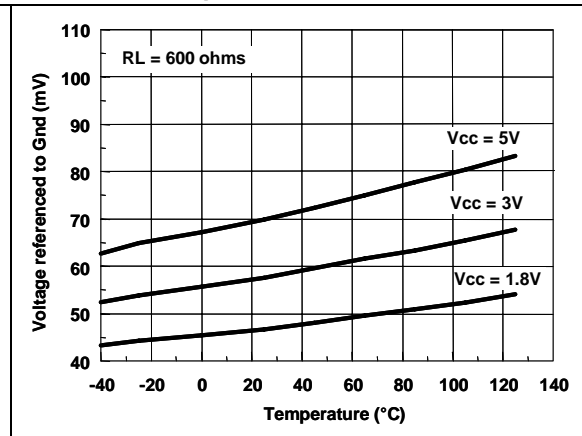


Figure 17. High level output voltage vs. temperature

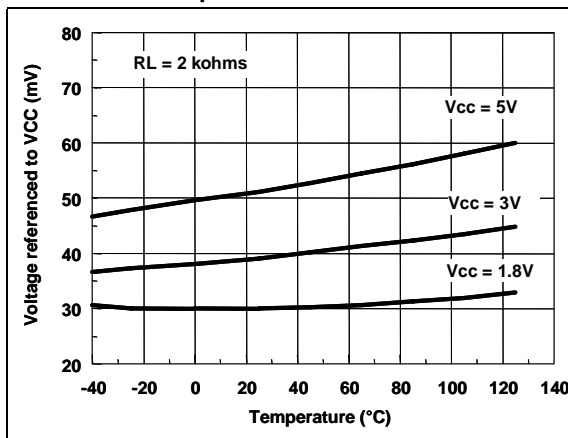


Figure 18. Low level output voltage vs. temperature

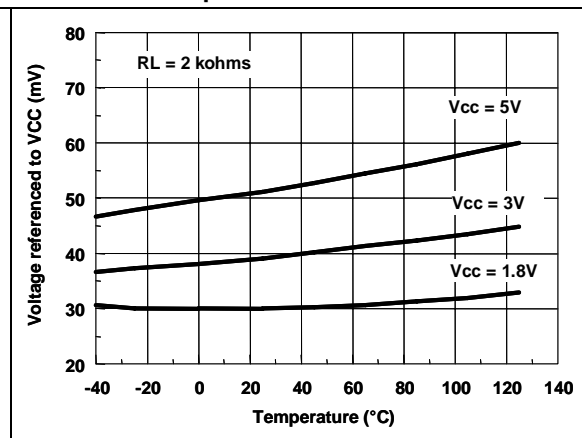


Figure 19. Output current vs. temperature

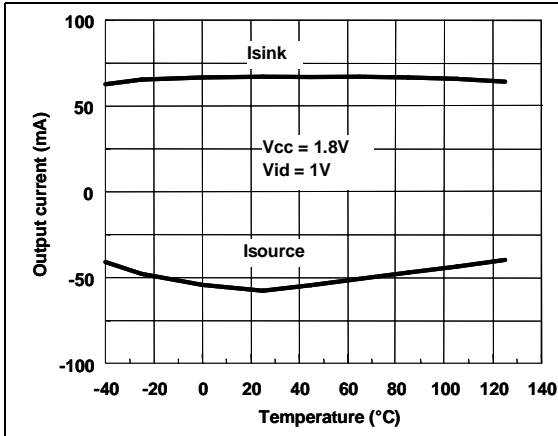


Figure 20. Output current vs. temperature

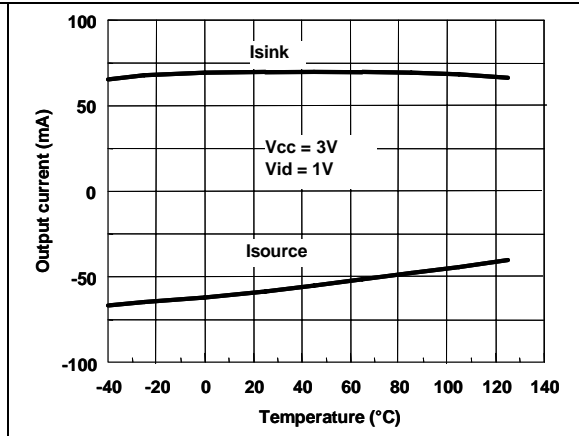


Figure 21. Output current vs. temperature

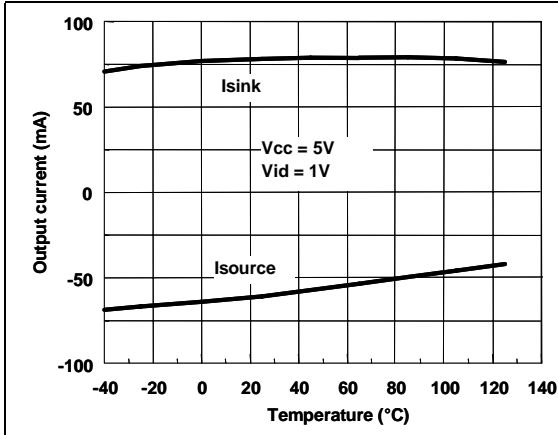


Figure 22. Output current vs. output voltage

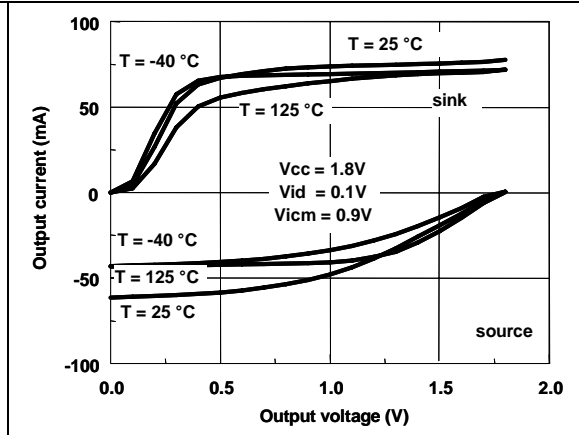


Figure 23. Output current vs. output voltage

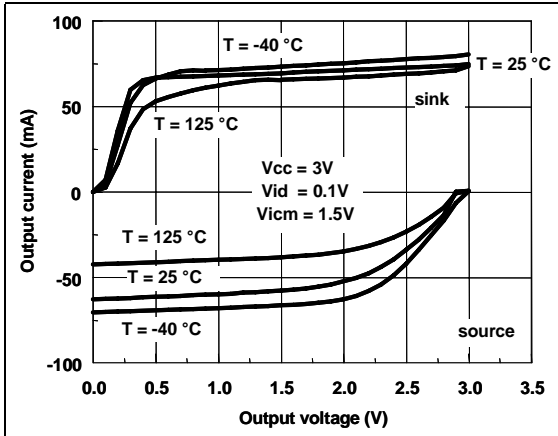


Figure 24. Output current vs. output voltage

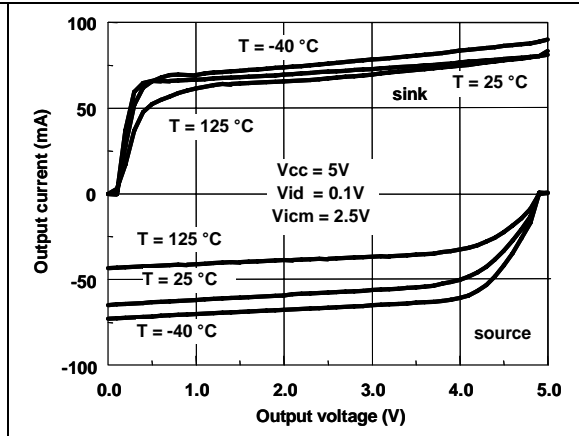


Figure 25. Gain and phase vs. frequency

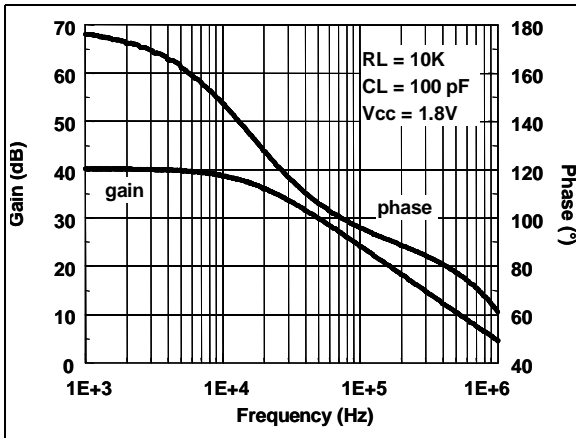


Figure 26. Gain and phase vs. frequency

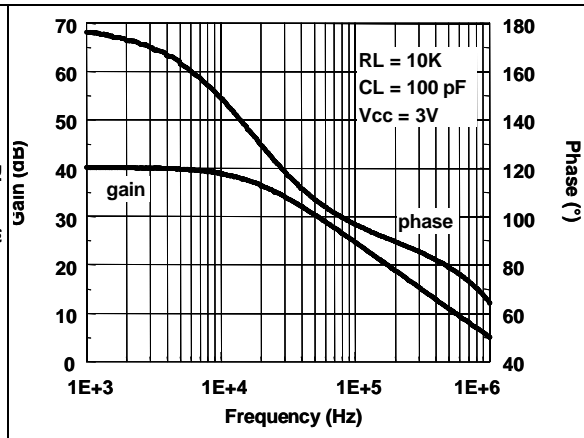


Figure 27. Gain and phase vs. frequency

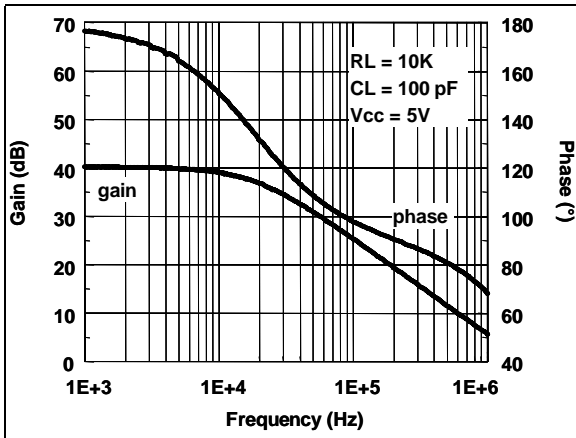


Figure 28. Gain bandwidth product vs. temperature

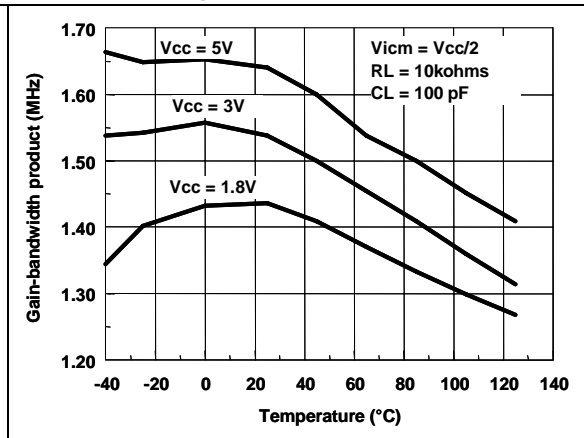


Figure 29. Gain bandwidth product vs. supply voltage

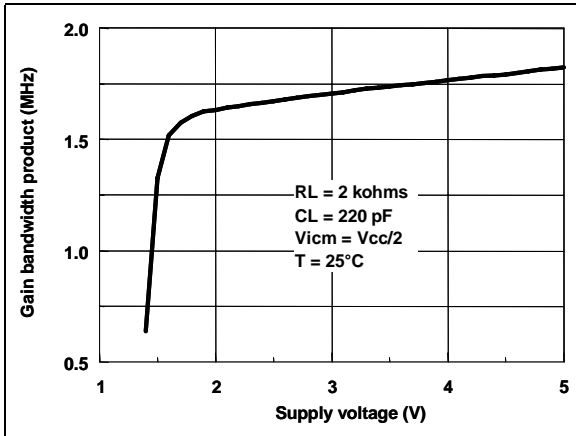


Figure 30. Slew rate vs. temperature

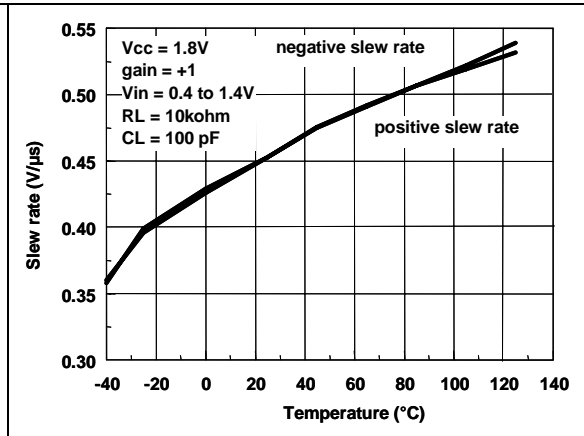


Figure 31. Slew rate vs. temperature

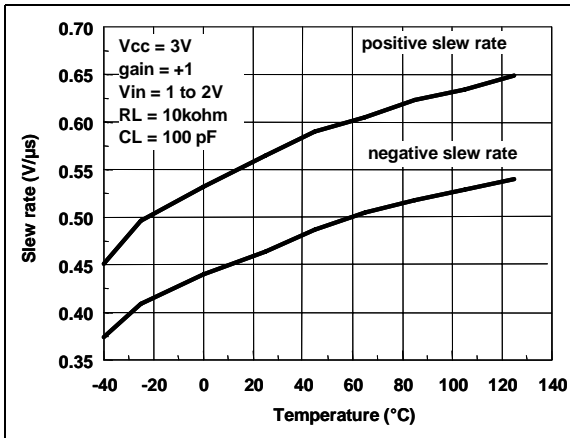


Figure 32. Slew rate vs. temperature

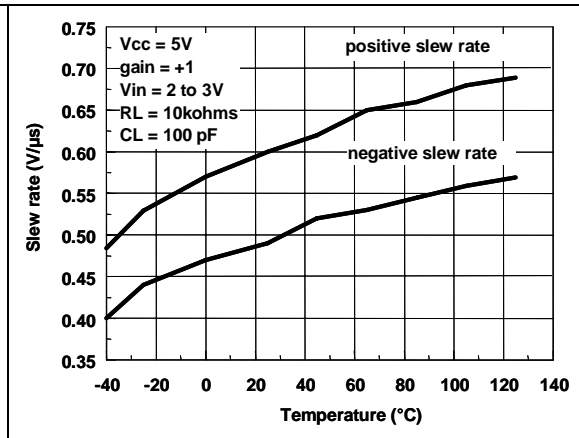


Figure 33. Phase margin vs. load capacitor

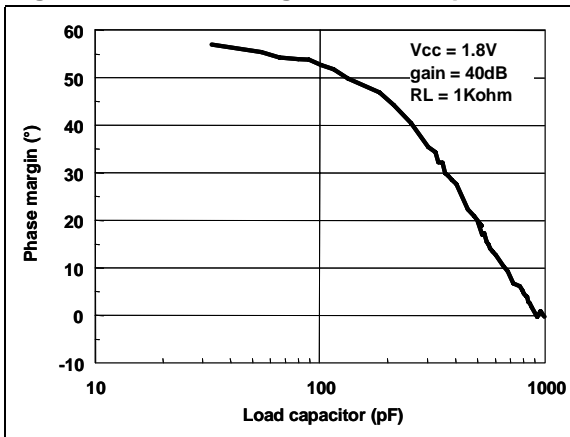


Figure 34. Phase margin vs. output current

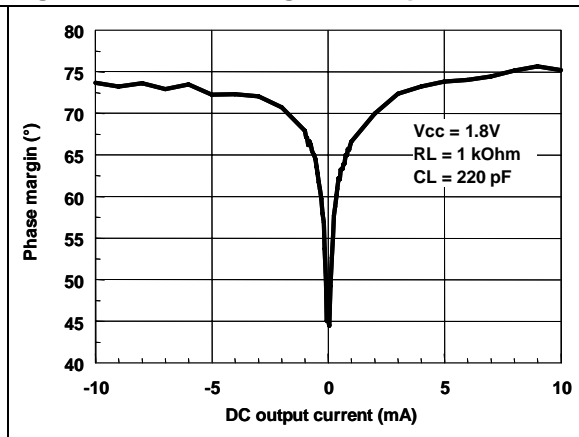


Figure 35. Gain margin vs. output current

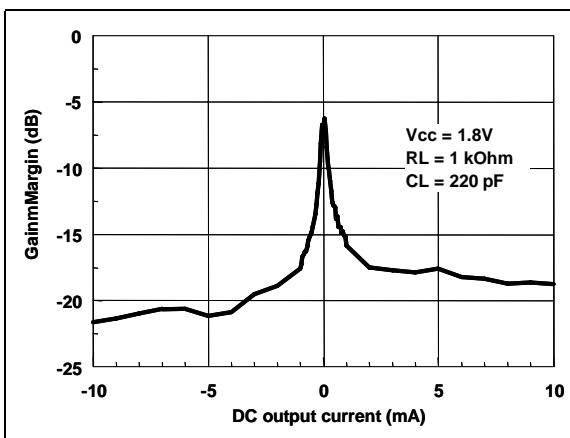


Figure 36. Equivalent input noise vs. frequency

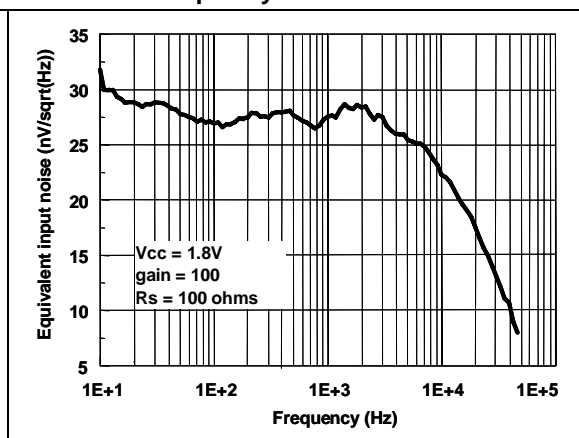


Figure 37. Distortion vs. output voltage

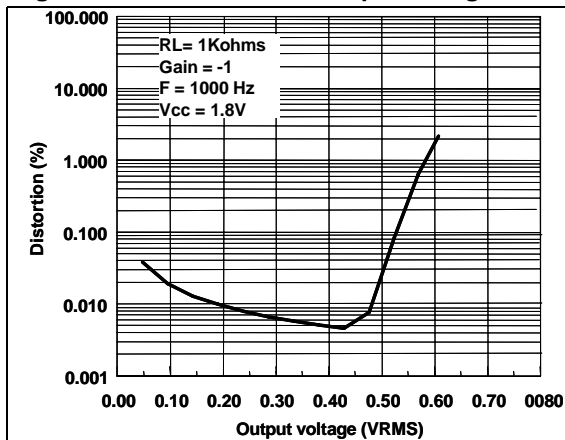


Figure 38. Distortion vs. output voltage

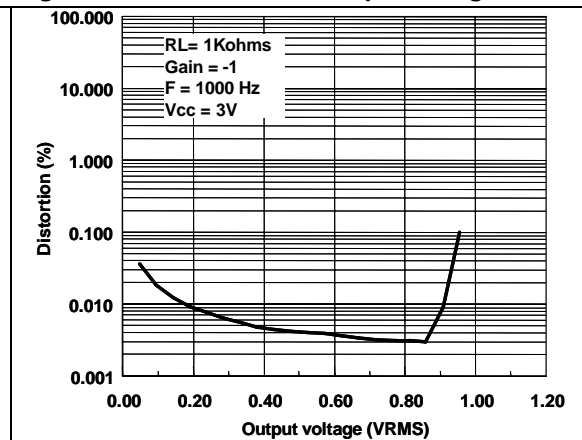


Figure 39. Distortion vs. output voltage

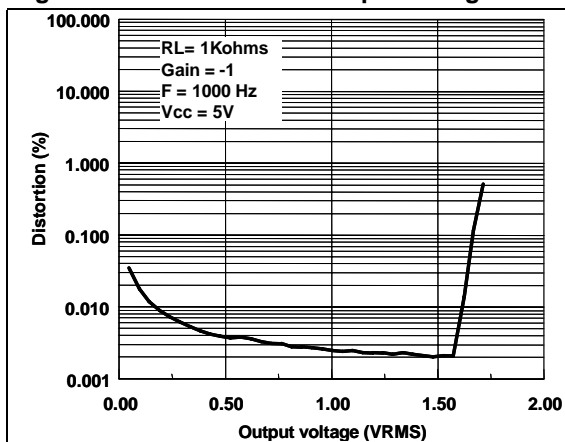


Figure 40. Distortion vs. output voltage

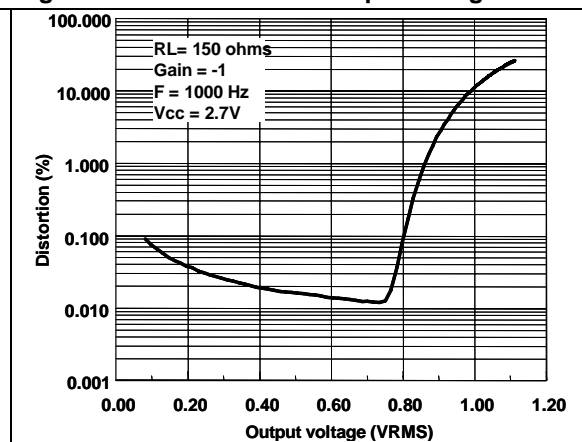


Figure 41. Distortion vs. output voltage

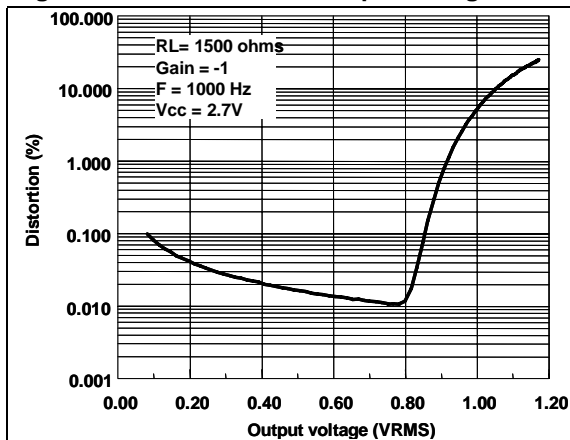


Figure 42. Distortion vs. output voltage

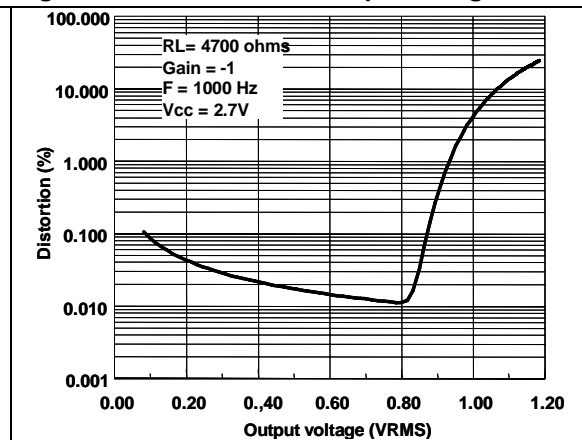


Figure 43. Distortion vs. frequency

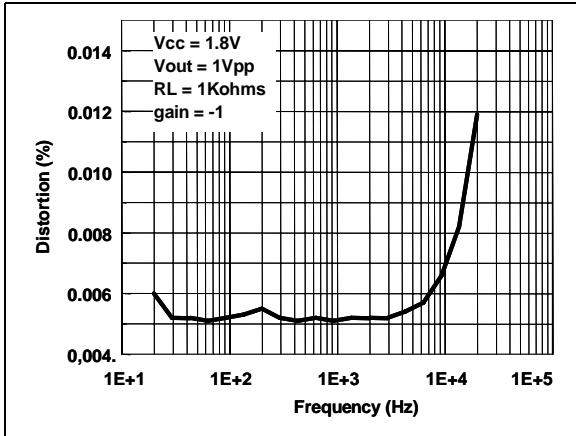


Figure 44. Distortion vs. frequency

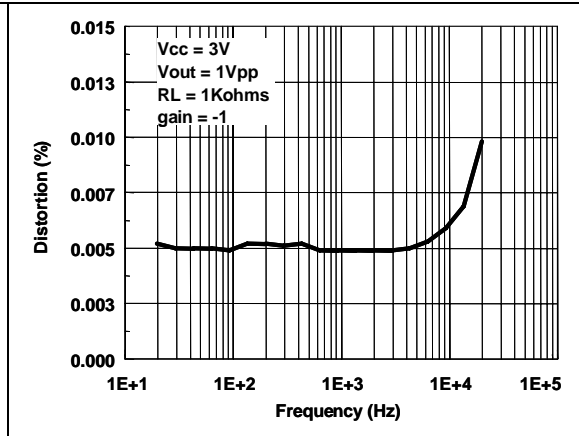


Figure 45. Distortion vs. frequency

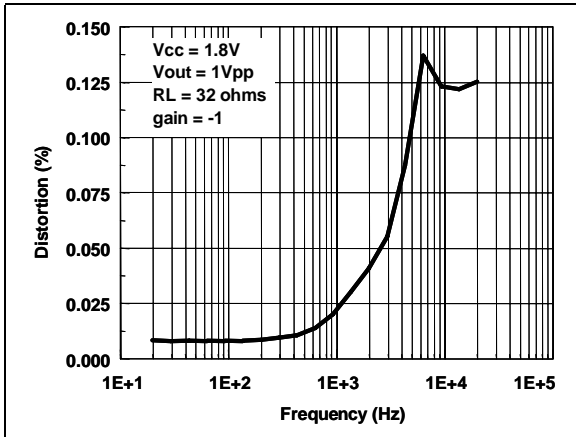


Figure 46. Distortion vs. frequency

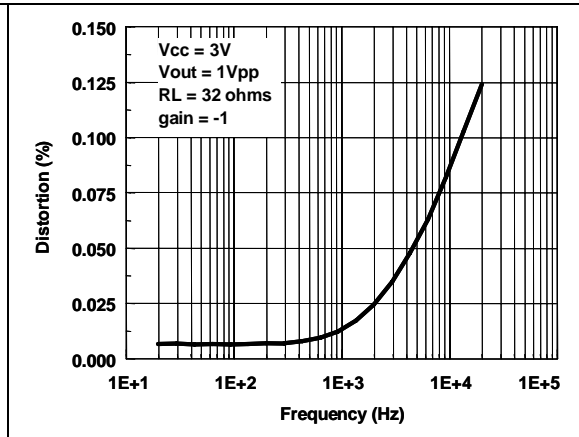
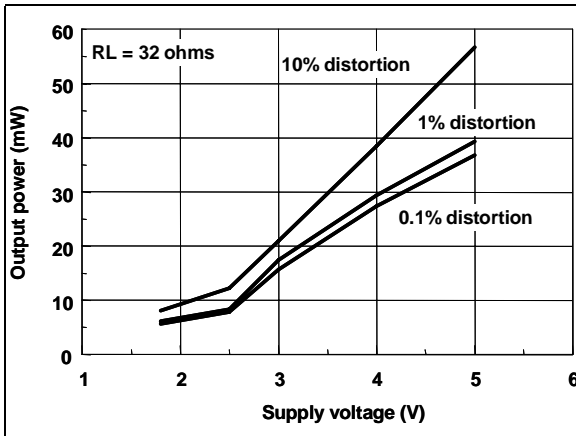


Figure 47. Output power vs. supply voltage

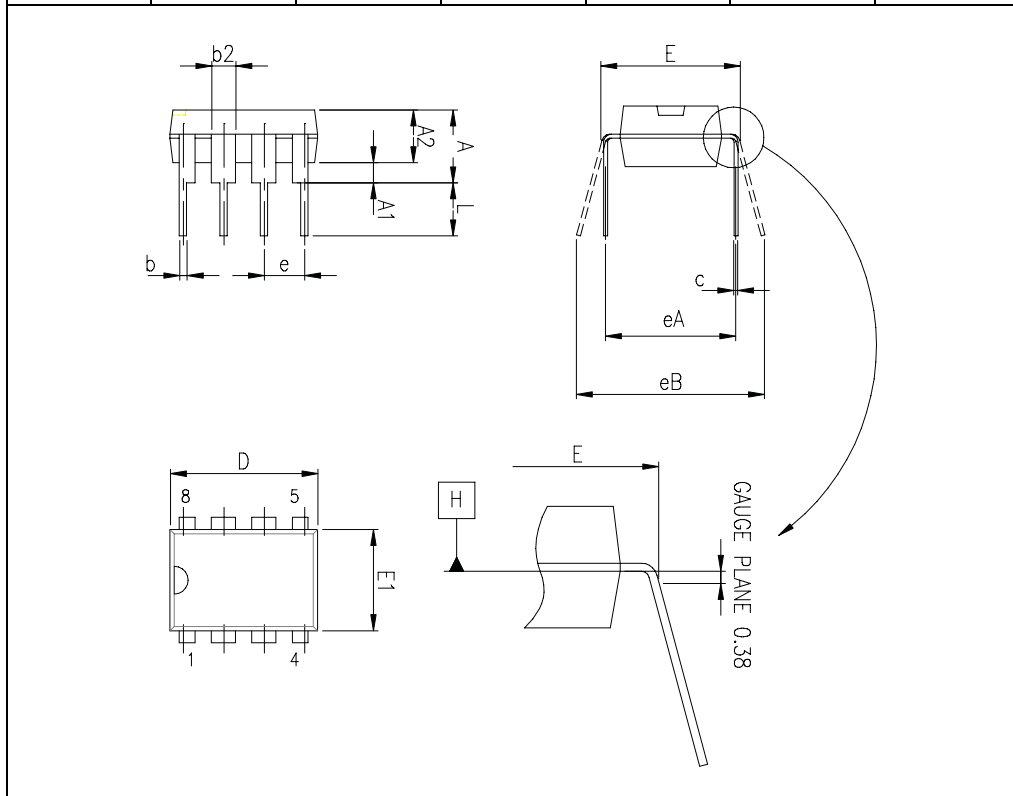


3 Package mechanical data

In order to meet environmental requirements, STMicroelectronics offers these devices in ECOPACK[®] packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an STMicroelectronics trademark. ECOPACK specifications are available at: www.st.com.

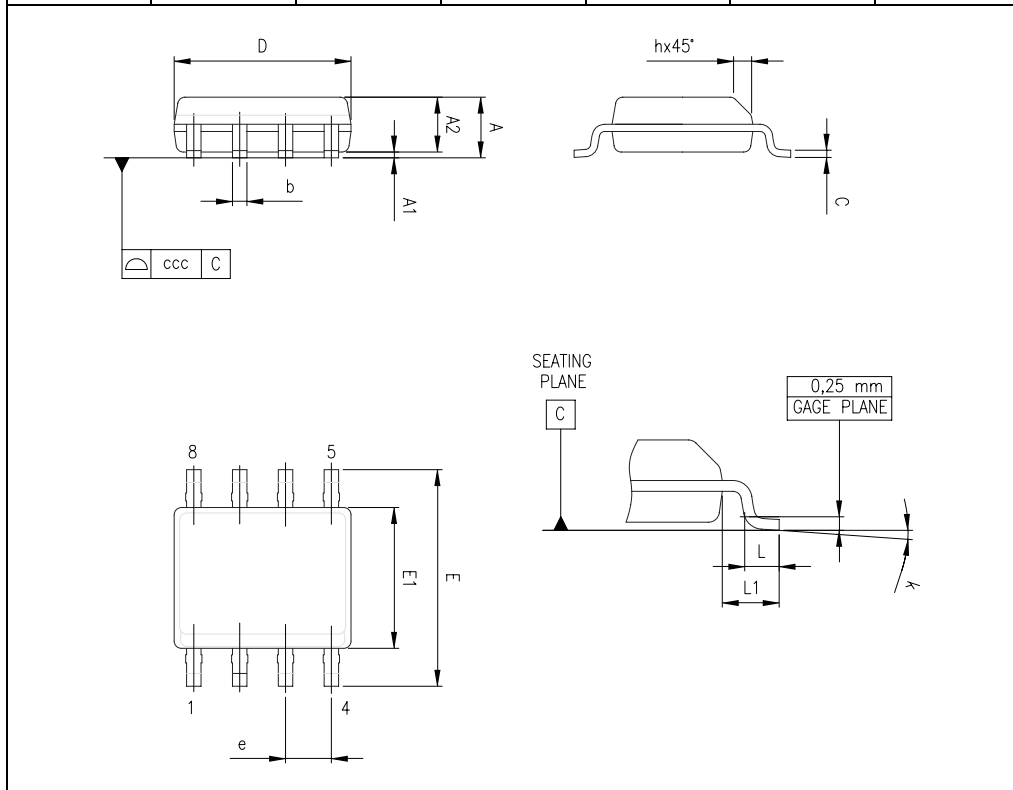
3.1 DIP8 package

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			5.33			0.210
A1	0.38			0.015		
A2	2.92	3.30	4.95	0.115	0.130	0.195
b	0.36	0.46	0.56	0.014	0.018	0.022
b2	1.14	1.52	1.78	0.045	0.060	0.070
c	0.20	0.25	0.36	0.008	0.010	0.014
D	9.02	9.27	10.16	0.355	0.365	0.400
E	7.62	7.87	8.26	0.300	0.310	0.325
E1	6.10	6.35	7.11	0.240	0.250	0.280
e		2.54			0.100	
eA		7.62			0.300	
eB			10.92			0.430
L	2.92	3.30	3.81	0.115	0.130	0.150



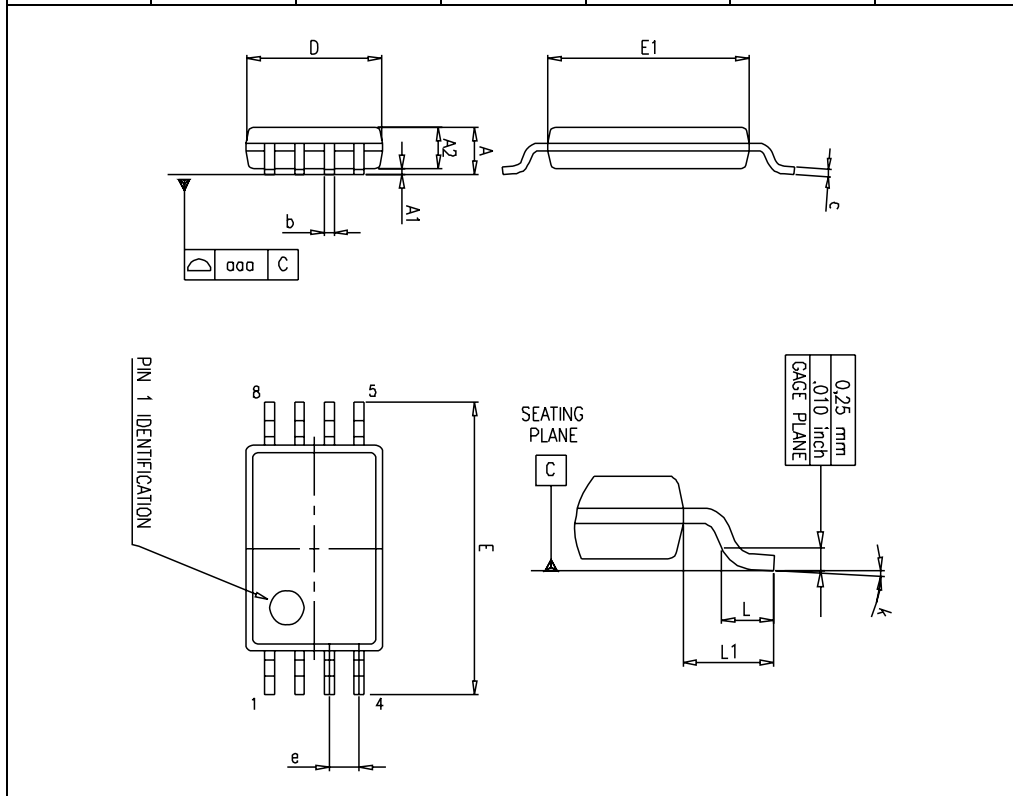
3.2 SO-8 package

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			1.75			0.069
A1	0.10		0.25	0.004		0.010
A2	1.25			0.049		
b	0.28		0.48	0.011		0.019
c	0.17		0.23	0.007		0.010
D	4.80	4.90	5.00	0.189	0.193	0.197
H	5.80	6.00	6.20	0.228	0.236	0.244
E1	3.80	3.90	4.00	0.150	0.154	0.157
e		1.27			0.050	
h	0.25		0.50	0.010		0.020
L	0.40		1.27	0.016		0.050
k	1°		8°	1°		8°
ccc			0.10			0.004



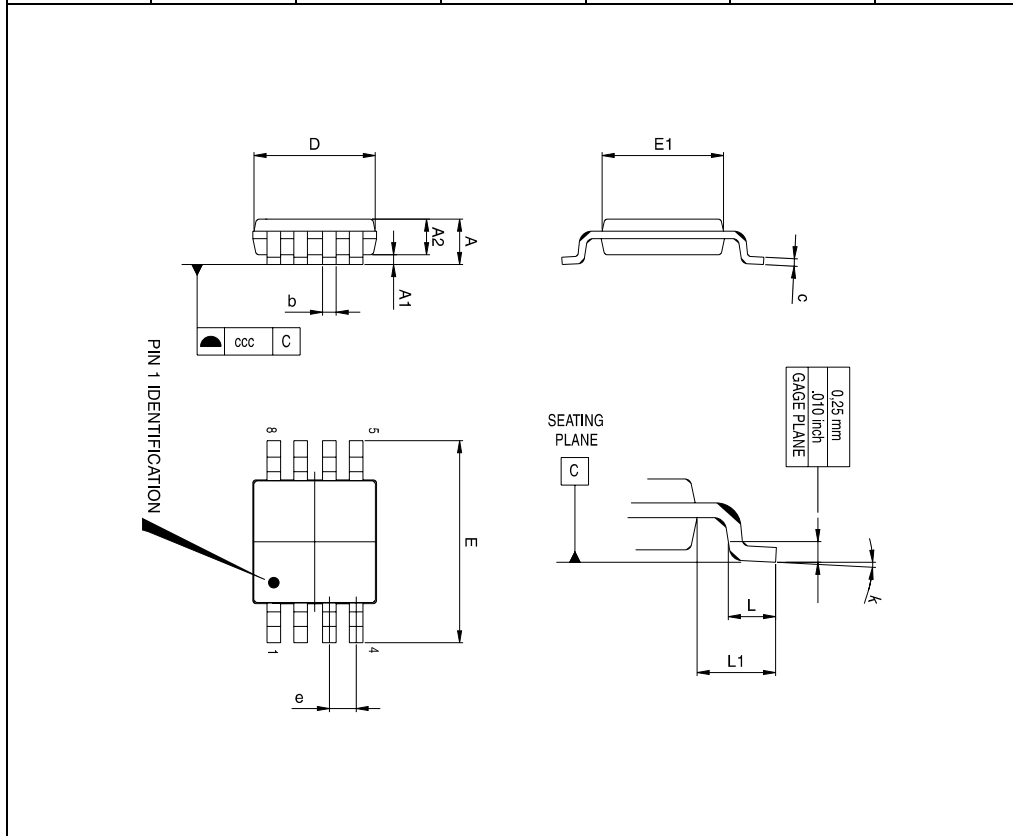
3.3 TSSOP8 package

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			1.2			0.047
A1	0.05		0.15	0.002		0.006
A2	0.80	1.00	1.05	0.031	0.039	0.041
b	0.19		0.30	0.007		0.012
c	0.09		0.20	0.004		0.008
D	2.90	3.00	3.10	0.114	0.118	0.122
E	6.20	6.40	6.60	0.244	0.252	0.260
E1	4.30	4.40	4.50	0.169	0.173	0.177
e		0.65			0.0256	
k	0°		8°	0°		8°
L	0.45	0.60	0.75	0.018	0.024	0.030
L1		1			0.039	
aaa		0.1			0.004	



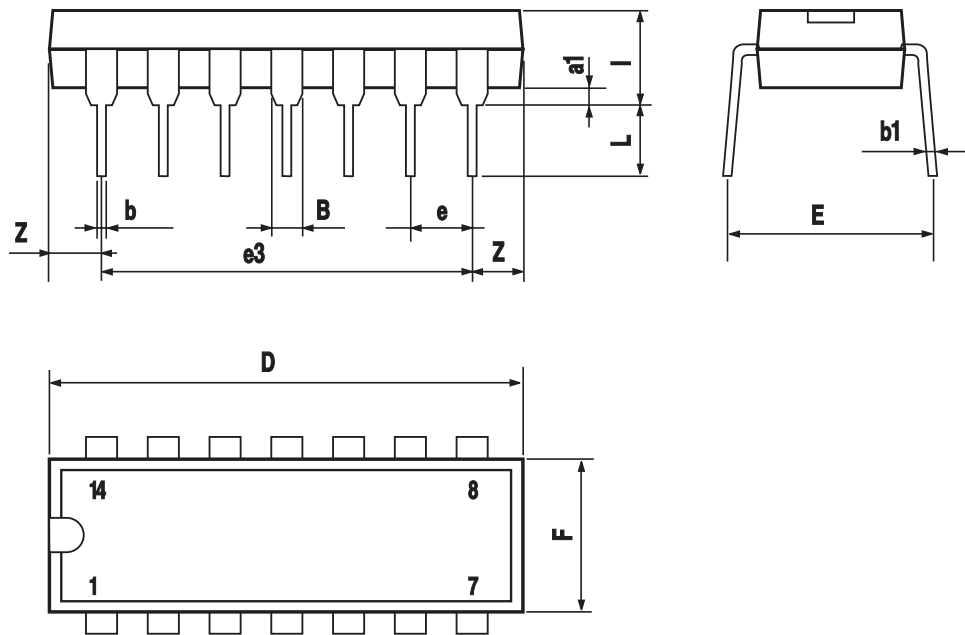
3.4 MiniSO-8 package

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			1.1			0.043
A1	0.05	0.10	0.15	0.002	0.004	0.006
A2	0.78	0.86	0.94	0.031	0.034	0.037
b	0.25	0.33	0.40	0.010	0.013	0.016
c	0.13	0.18	0.23	0.005	0.007	0.009
D	2.90	3.00	3.10	0.114	0.118	0.122
E	4.75	4.90	5.05	0.187	0.193	0.199
E1	2.90	3.00	3.10	0.114	0.118	0.122
e		0.65			0.026	
K	0°		6°	0°		6°
L	0.40	0.55	0.70	0.016	0.022	0.028
L1			0.10			0.004



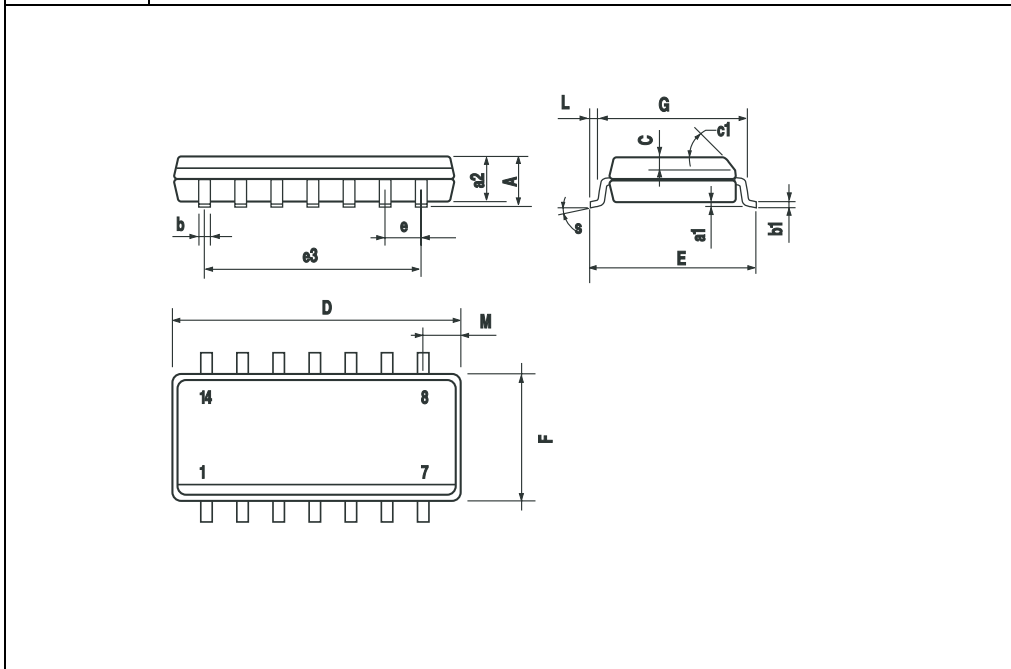
3.5 DIP14 package

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
a1	0.51			0.020		
B	1.39		1.65	0.055		0.065
b		0.5			0.020	
b1		0.25			0.010	
D			20			0.787
E		8.5			0.335	
e		2.54			0.100	
e3		15.24			0.600	
F			7.1			0.280
l			5.1			0.201
L		3.3			0.130	
Z	1.27		2.54	0.050		0.100



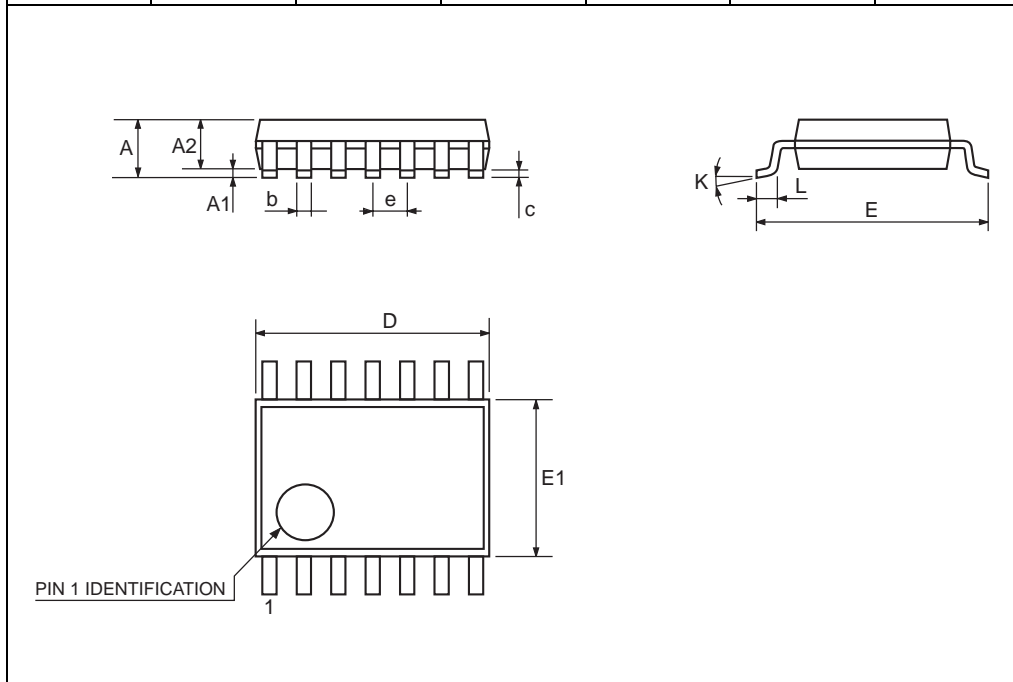
3.6 SO-14 package

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			1.75			0.068
a1	0.1		0.2	0.003		0.007
a2			1.65			0.064
b	0.35		0.46	0.013		0.018
b1	0.19		0.25	0.007		0.010
C		0.5			0.019	
c1	45° (typ.)					
D	8.55		8.75	0.336		0.344
E	5.8		6.2	0.228		0.244
e		1.27			0.050	
e3		7.62			0.300	
F	3.8		4.0	0.149		0.157
G	4.6		5.3	0.181		0.208
L	0.5		1.27	0.019		0.050
M			0.68			0.026
S	8° (max.)					



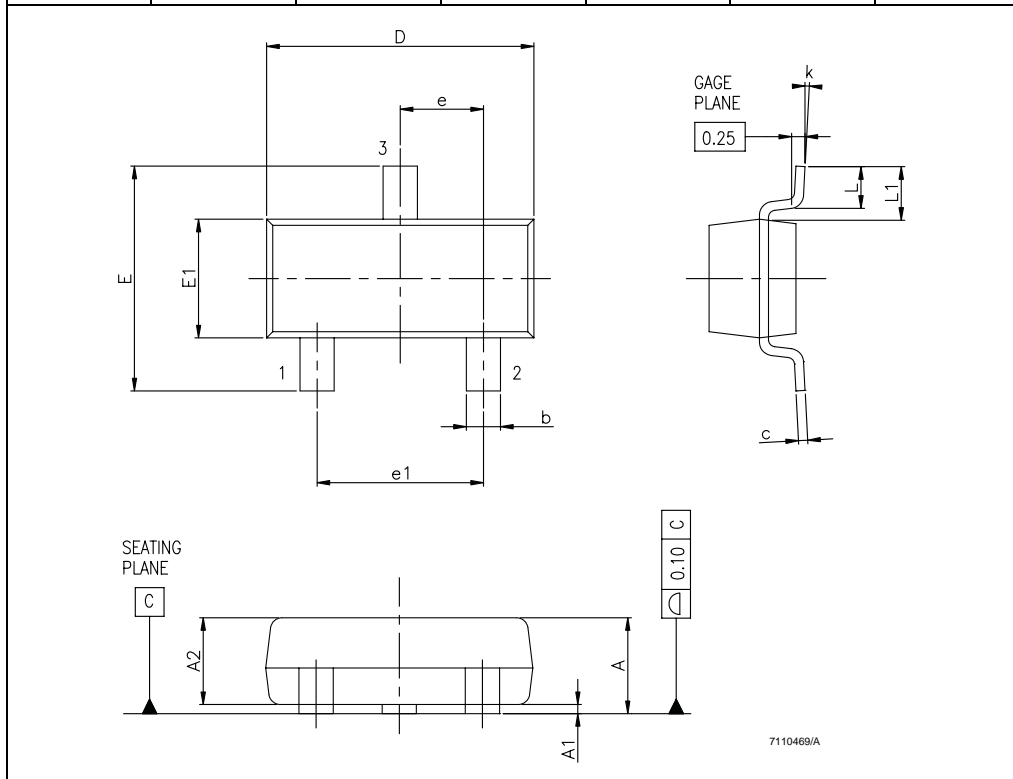
3.7 TSSOP14 package

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			1.2			0.047
A1	0.05		0.15	0.002	0.004	0.006
A2	0.8	1	1.05	0.031	0.039	0.041
b	0.19		0.30	0.007		0.012
c	0.09		0.20	0.004		0.0089
D	4.9	5	5.1	0.193	0.197	0.201
E	6.2	6.4	6.6	0.244	0.252	0.260
E1	4.3	4.4	4.48	0.169	0.173	0.176
e		0.65 BSC			0.0256 BSC	
K	0°		8°	0°		8°
L	0.45	0.60	0.75	0.018	0.024	0.030



3.8 SOT23-5 package

Ref.	Dimensions					
	Millimeters			Mils		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	0.890		1.120	35.05		44.12
A1	0.010		0.100	0.39		3.94
A2	0.880	0.950	1.020	34.65	37.41	40.17
b	0.300		0.500	11.81		19.69
C	0.080		0.200	3.15		7.88
D	2.800	2.900	3.040	110.26	114.17	119.72
E	2.100		2.64	82.70		103.96
E1	1.200	1.300	1.400	47.26	51.19	55.13
e		0.950			37.41	
e1		1.900			74.82	
L	0.400		0.600	15.75		23.63
L1		0.540			21.27	
k	0°		8°	0°		8°



4 Ordering information

Table 6. Order codes

Part number	Temperature range	Package	Packing	Marking
TS1871ID/IDT	-40°C, +125°C	SO-8	Tube or tape & reel	1871I
TS1871AID/AIDT				1871AI
TS1871IYD/IYDT ⁽¹⁾		SO-8 (Automotive grade)	Tube or tape & reel	1872Y
TS1871AIYD/AIYDT ⁽¹⁾				1872AY
TS1871ILT		SOT23-5L	Tape & reel	K171
TS1871AILT				K172
TS1871IYLT ⁽¹⁾		SOT23-5L (Automotive grade)	Tape & reel	K182
TS1871AIYLT ⁽¹⁾				K183
TS1872IN		DIP8	Tube	1872IN
TS1872AIN				1872AIN
TS1872ID/IDT		SO-8	Tube or tape & reel	1872I
TS1872AID/AIDT				1872AI
TS1872IYD/IYDT ⁽¹⁾		SO-8 (Automotive grade)	Tube or tape & reel	1872Y
TS1872AIYD/AIYDT ⁽¹⁾				1872AY
TS1872IPT		TSSOP8	Tape & reel	1872I
TS1872AIPT				1872A
TS1872IYPT ⁽¹⁾		TSSOP8 (Automotive grade)	Tape & reel	1872Y
TS1872AIYPT ⁽¹⁾				872AY
TS1872IST		MiniSO-8	Tape & reel	K171
TS1872AIST				K172
TS1874IN		DIP14	Tube	1874IN
TS1874AIN		DIP14	Tube	1874AIN
TS1874ID/IDT		SO-14	Tube or tape & reel	1874I
TS1874AID/AIDT				1874AI
TS1874IYD/IYDT ⁽¹⁾		SO-14 (Automotive grade)	Tube or tape & reel	TS1874Y
TS1874AIYD/AIYDT ⁽¹⁾				TS1874AY
TS1874IPT		TSSOP14	Tape & reel	1874I
TS1874AIPT				1874AI
TS1874IYPT ⁽¹⁾		TSSOP14 (Automotive grade)	Tape & reel	TS1874Y
TS1874AIYPT ⁽¹⁾				TS1874AY

1. Qualified and characterized according to AEC Q100 and Q003 or equivalent, advanced screening according to AEC Q001 & Q 002 or equivalent.

5 Revision history

Date	Revision	Changes
1-Apr-2002	1	First release.
2-Jan-2005	2	Modifications on AMR Table 1 on page 3 (explanation of V_{id} and V_i limits).
21-May-2007	4	Added limits in temperature in Table 3 on page 5 , Table 4 on page 6 , Table 5 on page 7 . Added SVR in Table 5 (SVR parameter removed from Table 3 and Table 4). Added equivalent input voltage noise in Table 3 , Table 4 , and Table 5 . Added R_{thjc} values in Table 1 . Added automotive grade part numbers to order codes table. Moved order codes table to Section 4 on page 25 . Updated format of package information.

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